UNITED STATES PATENT AND TRADEMARK OFFICE

# CERTIFICATE OF CORRECTION



PATENT NO. : 7,052,947 B2
APPLICATION NO. : 10/632154
DATED : May 30, 2006
INVENTOR(S) : Yi Ding

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

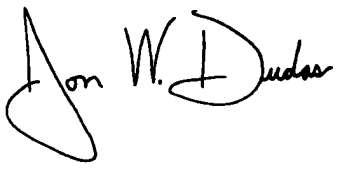
On Title page, item 73 please delete Assignee country "JP" and insert --TW--

Col. 12, line 9 after "(c)" insert --after--

Col. 12, line 11 after "memory cell" insert --, the floating and control gates being provided entirely by the one or more second layers, the floating and control gates comprising no protion of the first layer--

Signed and Sealed this

Eleventh Day of March, 2008



JON W. DUDAS
*Director of the United States Patent and Trademark Office*